Erratum (v. 5, n. 4, 427-432, 2002)

Due to problems in the desktop publishing, the article

Homogeneous Gaussian Profile P⁺-Type Emitters: Updated Parameters and Metal-Grid Optimization, by M. Cid, N. Stern*, was printed with figures caption error. The correct figures are:

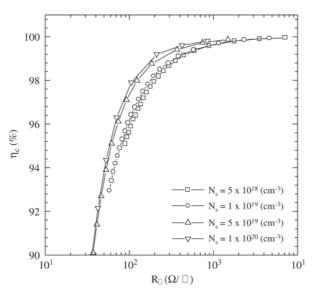


Figure 5. Emitter collection efficiency, η_c as function of emitter sheet resistivity, R_0 and surface doping level, N_s , considering passivated surfaces.

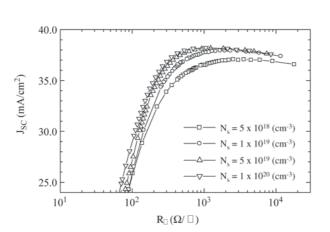


Figure 6. Short-circuit current density, J_{sc} as function of emitter sheet resistivity, R_{0} and surface doping level, N_{s} , considering ptype emitter solar cells.

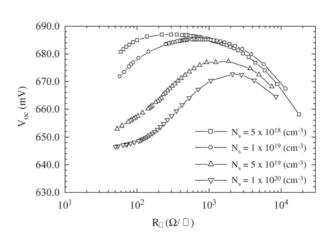


Figure 7. Open circuit voltage, V_{oc} as function of emitter sheet resistivity, R_0 and surface doping level, N_s , considering p-type emitter solar cells.

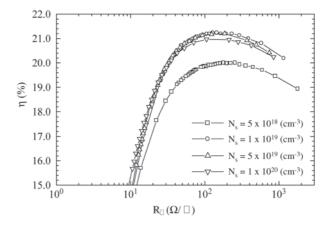


Figure 8. Efficiency, η as function of emitter sheet resistivity, $R_{_{\square}}$ and surface doping level, $N_{_{\upolimits}}$, considering p-type emitter solar cells.

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